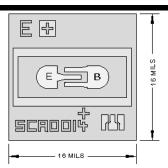


Chip Type 2C4261 Geometry 0014 Polarity PNP Data Sheet No. 2C4261

**Generic Packaged Parts:** 

**Request Quotation** 

2N4260, 2N4261



Chip type **2C4261** by Semicoa Semiconductors provides performance similar to these devices.

## Product Summary:

## APPLICATIONS:

Designed for low voltage, low gain RF amplifier applications.

## Part Numbers:

2N4261, 2N4261UB, 2N4260, 2N4260UB, SD4261, SD4261F, SQ4261, SQ4261F

## Features: Special Characteristics

ft = 1.8 GHz (typ) at 10 mA/10V

Mechanical Specifications					
Metallization	Тор	Al - 12 kÅ min.			
	Backside	Au - 6.5 kÅ nom.			
Bonding Pad Size	Emitter	2.1 mils x 2.1 mils			
	Base	2.1 mils x 2.1 mils			
Die Thickness	8 mils nominal				
Chip Area	16 mils x 16 mils				
Top Surface	Silox Passivated				

Electrical Characteristics						
$T_A = 25^{\circ}C$						
Parameter	Test conditions	Min	Max	Unit		
BV <sub>CEO</sub>	$I_{\rm C} = 10.0 \text{ mA}, I_{\rm B} = 0$	15		V dc		
BV <sub>CBO</sub>	$I_{C} = 10 \ \mu A, \ I_{E} = 0$	15		V dc		
BV <sub>EBO</sub>	$I_{\rm E} = 10 \ \mu A, \ I_{\rm C} = 0$	4.5		V dc		
h <sub>FE</sub>	$I_{C} = 10 \text{ mA dc}, V_{CE} = 1.0 \text{ V dc}$	30	150			

Due to limitations of probe testing, only dc parameters are tested. This must be done with pulse width less than 300  $\mu$ s, duty cycle less than 2%.